Lecture 16:Field Effect Transistors (FETs) (2)

MOSFET structure, Characteristics and parameters, Biasing of MOSFET, examples

MOSFET Transistor

The metal oxide semiconductor FET uses an insulated gate to isolate the gate from the channel. Two types are the enhancement mode (E-MOSFET) and the depletion mode (D-MOSFET).

An E-MOSFET has no channel until it is induced by a voltage applied to the gate, so it operates only in enhancement mode. An *n*channel type is illustrated here; a positive gate voltage induces the channel.



D-MOSFET

The D-MOSFET has a channel that can be controlled by the gate voltage. For an *n*-channel type, a negative voltage depletes the channel; and a positive voltage enhances the channel.

A D-MOSFET can operate in either mode, depending on the gate voltage.



Circuit Symbols of MOSFETs

MOSFET symbols are shown. Notice the broken line representing the E-MOSFET that has an induced channel. The n channel has an i<u>n</u>ward pointing arrow.



Transfer Curves of E-MOSFET

The transfer curve for a MOSFET has the same parabolic shape as the JFET but the position is shifted along the *x*-axis. The transfer curve for an *n*-channel E-MOSFET is entirely in the first quadrant as shown

The curve starts at $V_{GS(th)}$, which is a nonzero voltage that is required to have channel conduction. The equation for the drain current is $I_{\rm D} = K (V_{\rm GS} - V_{\rm GS(th)})^2$



Transfer Curves of D-MOSFET

Recall that the D-MOSFET can be operated in either mode. For the *n*-channel device illustrated, operation to the left of the *y*-axis means it is in depletion mode; operation to the right means is in enhancement mode.

As with the JFET, I_D is zero at $V_{GS(off)}$. When VGS is 0, the drain current is IDSS, which for this device is *not* the maximum current. The equation for drain current is

$$I_{\rm D} \cong I_{\rm DSS} \left(1 - \frac{V_{\rm GS}}{V_{\rm GS(off)}} \right)^2$$



Biasing of E-MOSFET

E-MOSFETs can be biased using bias methods like the JFETS and BJTs. Voltage-divider bias and drain-feedback bias are illustrated for *n*-channel devices.





Voltage-divider bias

Drain-feedback bias

Biasing of a D-MOSFET

The simplest way to bias a D-MOSFET is with zero bias. This works because the device can operate in either depletion or enhancement mode, so the gate can go above or below 0 V.

